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Understanding Embedded - FPGAs (Field Programmable Gate Array)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Obsolete
Number of LABs/CLBs	600
Number of Logic Elements/Cells	2700
Total RAM Bits	81920
Number of I/O	158
Number of Gates	128236
Voltage - Supply	1.71V ~ 1.89V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	240-BFQFP
Supplier Device Package	240-PQFP (32x32)
Purchase URL	https://www.e-xfl.com/product-detail/xilinx/xcv100e-6pq240i

forces a storage element into the initialization state specified for it in the configuration. BY forces it into the opposite state. Alternatively, these signals can be configured to operate asynchronously. All of the control signals are independently invertible, and are shared by the two flip-flops within the slice.

Additional Logic

The F5 multiplexer in each slice combines the function generator outputs. This combination provides either a function generator that can implement any 5-input function, a 4:1 multiplexer, or selected functions of up to nine inputs.

Similarly, the F6 multiplexer combines the outputs of all four function generators in the CLB by selecting one of the F5-multiplexer outputs. This permits the implementation of any 6-input function, an 8:1 multiplexer, or selected functions of up to 19 inputs.

Each CLB has four direct feedthrough paths, two per slice. These paths provide extra data input lines or additional local routing that does not consume logic resources.

Arithmetic Logic

Dedicated carry logic provides fast arithmetic carry capability for high-speed arithmetic functions. The Virtex-E CLB supports two separate carry chains, one per Slice. The height of the carry chains is two bits per CLB.

The arithmetic logic includes an XOR gate that allows a 2-bit full adder to be implemented within a slice. In addition, a dedicated AND gate improves the efficiency of multiplier implementation. The dedicated carry path can also be used to cascade function generators for implementing wide logic functions.

BUFTs

Each Virtex-E CLB contains two 3-state drivers (BUFTs) that can drive on-chip buses. See **Dedicated Routing**. Each Virtex-E BUFT has an independent 3-state control pin and an independent input pin.

Block SelectRAM

Virtex-E FPGAs incorporate large block SelectRAM memories. These complement the Distributed SelectRAM memories that provide shallow RAM structures implemented in CLBs.

Block SelectRAM memory blocks are organized in columns, starting at the left (column 0) and right outside edges and inserted every 12 CLB columns (see notes for smaller devices). Each memory block is four CLBs high, and each memory column extends the full height of the chip, immediately adjacent (to the right, except for column 0) of the CLB column locations indicated in Table 3.

Table 3: **CLB/Block RAM Column Locations**

XCV Device /Col.	0	12	24	36	48	60	72	84	96	108	120	138	156
50E	Columns 0, 6, 18, & 24												
100E	Columns 0, 12, 18, & 30												
200E	Columns 0, 12, 30, & 42												
300E	√	√		√	√								
400E	√	√			√	√							
600E	√	√	√		√	√	√						
1000E	√	√	√				√	√	√				
1600E	√	√	√	√			√	√	√	√			
2000E	√	√	√	√				√	√	√	√		
2600E	√	√	√	√					√	√	√	√	
3200E	√	√	√	√						√	√	√	√

Table 4 shows the amount of block SelectRAM memory that is available in each Virtex-E device.

Table 4: **Virtex-E Block SelectRAM Amounts**

Virtex-E Device	# of Blocks	Block SelectRAM Bits
XCV50E	16	65,536
XCV100E	20	81,920
XCV200E	28	114,688
XCV300E	32	131,072
XCV400E	40	163,840
XCV600E	72	294,912
XCV1000E	96	393,216
XCV1600E	144	589,824
XCV2000E	160	655,360
XCV2600E	184	753,664
XCV3200E	208	851,968

As illustrated in Figure 6, each block SelectRAM cell is a fully synchronous dual-ported (True Dual Port) 4096-bit RAM with independent control signals for each port. The data widths of the two ports can be configured independently, providing built-in bus-width conversion.

represents a combination of the LVTTL IBUFG and BUFG symbols, such that the output of the BUFGP can connect directly to the clock pins throughout the design.

Unlike previous architectures, the Virtex-E BUFGP symbol can only be placed in a global clock pad location. The LOC property can specify a location for the BUFGP.

OBUF

An OBUF must drive outputs through an external output port. The generic output buffer (OBUF) symbol appears in Figure 40.

The extension to the base name defines which I/O standard the OBUF uses. With no extension specified for the generic OBUF symbol, the assumed standard is slew rate limited LVTTL with 12 mA drive strength.

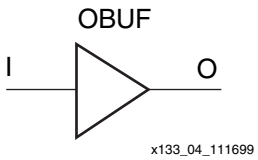


Figure 40: **Virtex-E Output Buffer (OBUF) Symbol**

The LVTTL OBUF additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

LVTTL output buffers have selectable drive strengths.

The format for LVTTL OBUF symbol names is as follows:

OBUF_<slew_rate>_<drive_strength>

where <slew_rate> is either F (Fast) or S (Slow), and <drive_strength> is specified in milliamps (2, 4, 6, 8, 12, 16, or 24).

The following list details variations of the OBUF symbol.

- OBUF
- OBUF_S_2
- OBUF_S_4
- OBUF_S_6
- OBUF_S_8
- OBUF_S_12
- OBUF_S_16
- OBUF_S_24
- OBUF_F_2
- OBUF_F_4
- OBUF_F_6
- OBUF_F_8
- OBUF_F_12
- OBUF_F_16
- OBUF_F_24
- OBUF_LVCMOS2
- OBUF_PCI33_3
- OBUF_PCI66_3
- OBUF_GTL
- OBUF_GTLP
- OBUF_HSTL_I
- OBUF_HSTL_III
- OBUF_HSTL_IV
- OBUF_SSTL3_I
- OBUF_SSTL3_II
- OBUF_SSTL2_I
- OBUF_SSTL2_II
- OBUF_CTT
- OBUF_AGP
- OBUF_LVCMOS18
- OBUF_LVDS
- OBUF_LVPECL

The Virtex-E series supports eight banks for the HQ and PQ packages. The CS packages support four V_{CCO} banks.

OBUF placement restrictions require that within a given V_{CCO} bank each OBUF share the same output source drive voltage. Input buffers of any type and output buffers that do not require V_{CCO} can be placed within any V_{CCO} bank. Table 20 summarizes the Virtex-E output compatibility requirements. The LOC property can specify a location for the OBUF.

Table 20: **Output Standards Compatibility Requirements**

Rule 1	Only outputs with standards that share compatible V_{CCO} can be used within the same bank.
Rule 2	There are no placement restrictions for outputs with standards that do not require a V_{CCO}.
V_{CCO}	Compatible Standards
3.3	LVTTL, SSTL3_I, SSTL3_II, CTT, AGP, GTL, GTL+, PCI33_3, PCI66_3
2.5	SSTL2_I, SSTL2_II, LVCMOS2, GTL, GTL+
1.5	HSTL_I, HSTL_III, HSTL_IV, GTL, GTL+

OBUFT

The generic 3-state output buffer OBUFT (see Figure 41) typically implements 3-state outputs or bidirectional I/O.

The extension to the base name defines which I/O standard OBUFT uses. With no extension specified for the generic OBUFT symbol, the assumed standard is slew rate limited LVTTL with 12 mA drive strength.

The LVTTL OBUFT additionally can support one of two slew rate modes to minimize bus transients. By default, the slew rate for each output buffer is reduced to minimize power bus transients when switching non-critical signals.

Input termination techniques include the following.

- None
- Parallel (Shunt)

These termination techniques can be applied in any combination. A generic example of each combination of termination methods appears in Figure 43.

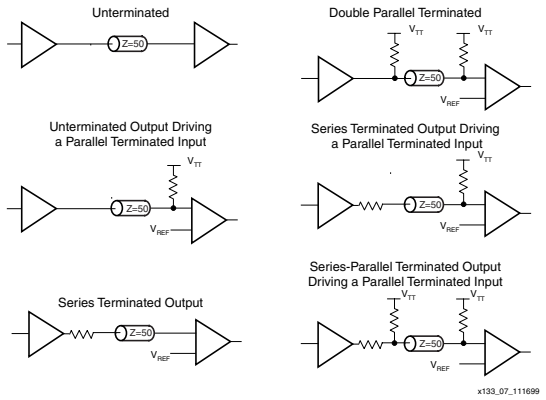


Figure 43: **Overview of Standard Input and Output Termination Methods**

Simultaneous Switching Guidelines

Ground bounce can occur with high-speed digital ICs when multiple outputs change states simultaneously, causing undesired transient behavior on an output, or in the internal logic. This problem is also referred to as the Simultaneous Switching Output (SSO) problem.

Ground bounce is primarily due to current changes in the combined inductance of ground pins, bond wires, and ground metallization. The IC internal ground level deviates from the external system ground level for a short duration (a few nanoseconds) after multiple outputs change state simultaneously.

Ground bounce affects stable Low outputs and all inputs because they interpret the incoming signal by comparing it to the internal ground. If the ground bounce amplitude exceeds the actual instantaneous noise margin, then a non-changing input can be interpreted as a short pulse with a polarity opposite to the ground bounce.

Table 21 provides guidelines for the maximum number of simultaneously switching outputs allowed per output power/ground pair to avoid the effects of ground bounce. See Table 22 for the number of effective output power/ground pairs for each Virtex-E device and package combination.

Table 21: **Guidelines for Max Number of Simultaneously Switching Outputs per Power/Ground Pair**

Standard	Package		
	BGA, CS, FGA	HQ	PQ, TQ
LVTTL Slow Slew Rate, 2 mA drive	68	49	36
LVTTL Slow Slew Rate, 4 mA drive	41	31	20
LVTTL Slow Slew Rate, 6 mA drive	29	22	15
LVTTL Slow Slew Rate, 8 mA drive	22	17	12
LVTTL Slow Slew Rate, 12 mA drive	17	12	9
LVTTL Slow Slew Rate, 16 mA drive	14	10	7
LVTTL Slow Slew Rate, 24 mA drive	9	7	5
LVTTL Fast Slew Rate, 2 mA drive	40	29	21
LVTTL Fast Slew Rate, 4 mA drive	24	18	12
LVTTL Fast Slew Rate, 6 mA drive	17	13	9
LVTTL Fast Slew Rate, 8 mA drive	13	10	7
LVTTL Fast Slew Rate, 12 mA drive	10	7	5
LVTTL Fast Slew Rate, 16 mA drive	8	6	4
LVTTL Fast Slew Rate, 24 mA drive	5	4	3
LVCMOS	10	7	5
PCI	8	6	4
GTL	4	4	4
GTL+	4	4	4

Date	Version	Revision
9/20/00	1.7	• Min values added to **Virtex-E Electrical Characteristics** tables. • XCV2600E and XCV3200E numbers added to **Virtex-E Electrical Characteristics** tables (Module 3). • Corrected user I/O count for XCV100E device in Table 1 (Module 1). • Changed several pins to “No Connect in the XCV100E“ and removed duplicate V_{CCINT} pins in Table ~ (Module 4). • Changed pin J10 to “No connect in XCV600E” in Table 74 (Module 4). • Changed pin J30 to “VREF option only in the XCV600E” in Table 74 (Module 4). • Corrected pair 18 in Table 75 (Module 4) to be “AO in the XCV1000E, XCV1600E“.
11/20/00	1.8	• Upgraded speed grade -8 numbers in **Virtex-E Electrical Characteristics** tables to Preliminary. • Updated minimums in Table 13 and added notes to Table 14. • Added to note 2 to **Absolute Maximum Ratings**. • Changed speed grade -8 numbers for $T_{SHCKO32}$, T_{REG}, T_{BCCS}, and T_{ICKOF}. • Changed all minimum hold times to –0.4 under **Global Clock Set-Up and Hold for LVTTL Standard, with DLL**. • Revised maximum T_{DLLPW} in -6 speed grade for **DLL Timing Parameters**. • Changed GCLK0 to BA22 for FG860 package in Table 46.
2/12/01	1.9	• Revised footnote for Table 14. • Added numbers to **Virtex-E Electrical Characteristics** tables for XCV1000E and XCV2000E devices. • Updated Table 27 and Table 78 to include values for XCV400E and XCV600E devices. • Revised Table 62 to include pinout information for the XCV400E and XCV600E devices in the BG560 package. • Updated footnotes 1 and 2 for Table 76 to include XCV2600E and XCV3200E devices.
4/02/01	2.0	• Updated numerous values in **Virtex-E Switching Characteristics** tables. • Converted data sheet to modularized format. See the **Virtex-E Data Sheet** section.
4/19/01	2.1	• Modified Figure 30 "DLL Generation of 4x Clock in Virtex-E Devices."
07/23/01	2.2	• Made minor edits to text under **Configuration**. • Added CLB column locations for XCV2600E anbd XCV3200E devices in Table 3.
11/09/01	2.3	• Added warning under **Configuration** section that attempting to load an incorrect bitstream causes configuration to fail and can damage the device.
07/17/02	2.4	• Data sheet designation upgraded from Preliminary to Production.
09/10/02	2.5	• Added clarification to the **Input/Output Block**, **Configuration**, **Boundary Scan Mode**, and **Block SelectRAM** sections. Revised Figure 18, Table 11, and Table 36.
11/19/02	2.6	• Added clarification in the **Boundary Scan** section. • Removed last sentence regarding deactivation of duty-cycle correction in **Duty Cycle Correction Property** section.
06/15/04	2.6.1	• Updated clickable web addresses.
01/12/06	2.7	• Updated the **Slave-Serial Mode** and the **Master-Serial Mode** sections.
01/16/06	2.8	• Made minor updates to Table 8.

Virtex-E Electrical Characteristics

Definition of Terms

Electrical and switching characteristics are specified on a per-speed-grade basis and can be designated as Advance, Preliminary, or Production. Each designation is defined as follows:

Advance: These speed files are based on simulations only and are typically available soon after device design specifications are frozen. Although speed grades with this designation are considered relatively stable and conservative, some under-reporting might still occur.

Preliminary: These speed files are based on complete ES (engineering sample) silicon characterization. Devices and speed grades with this designation are intended to give a better indication of the expected performance of production silicon. The probability of under-reporting delays is greatly reduced as compared to Advance data.

Production: These speed files are released once enough production silicon of a particular device family member has been characterized to provide full correlation between speed files and devices over numerous production lots. There is no under-reporting of delays, and customers receive formal notification of any subsequent changes. Typically, the slowest speed grades transition to Production before faster speed grades.

All specifications are representative of worst-case supply voltage and junction temperature conditions. The parameters included are common to popular designs and typical applications. Contact the factory for design considerations requiring more detailed information.

Table 1 correlates the current status of each Virtex-E device with a corresponding speed file designation.

Table 1: **Virtex-E Device Speed Grade Designations**

Device	Speed Grade Designations		
	Advance	Preliminary	Production
XCV50E			–8, –7, –6
XCV100E			–8, –7, –6
XCV200E			–8, –7, –6
XCV300E			–8, –7, –6
XCV400E			–8, –7, –6
XCV600E			–8, –7, –6
XCV1000E			–8, –7, –6
XCV1600E			–8, –7, –6
XCV2000E			–8, –7, –6
XCV2600E			–8, –7, –6
XCV3200E			–8, –7, –6

All specifications are subject to change without notice.

DC Characteristics

Absolute Maximum Ratings

Symbol	Description[1]			Units
V_{CCINT}	Internal Supply voltage relative to GND		–0.5 to 2.0	V
V_{CCO}	Supply voltage relative to GND		–0.5 to 4.0	V
V_{REF}	Input Reference Voltage		–0.5 to 4.0	V
V_{IN} [3]	Input voltage relative to GND		–0.5 to V_{CCO} +0.5	V
V_{TS}	Voltage applied to 3-state output		–0.5 to 4.0	V
V_{CC}	Longest Supply Voltage Rise Time from 0 V - 1.71 V		50	ms
T_{STG}	Storage temperature (ambient)		–65 to +150	°C
T_J	Junction temperature [2]	Plastic packages	+125	°C

Notes:
1. Stresses beyond those listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those listed under Operating Conditions is not implied. Exposure to Absolute Maximum Ratings conditions for extended periods of time can affect device reliability.
2. For soldering guidelines and thermal considerations, see the device packaging information on www.xilinx.com.
3. Inputs configured as PCI are fully PCI compliant. This statement takes precedence over any specification that would imply that the device is not PCI compliant.

Recommended Operating Conditions

Symbol	Description		Min	Max	Units
V_{CCINT}	Internal Supply voltage relative to GND, T_J = 0 °C to +85 °C	Commercial	1.8 – 5%	1.8 + 5%	V
	Internal Supply voltage relative to GND, T_J = –40 °C to +100 °C	Industrial	1.8 – 5%	1.8 + 5%	V
V_{CCO}	Supply voltage relative to GND, T_J = 0 °C to +85 °C	Commercial	1.2	3.6	V
	Supply voltage relative to GND, T_J = –40 °C to +100 °C	Industrial	1.2	3.6	V
T_{IN}	Input signal transition time			250	ns

CLB Distributed RAM Switching Characteristics

Description	Symbol	Speed Grade(1)				Units
		Min	-8	-7	-6	
Sequential Delays						
Clock CLK to X/Y outputs (WE active) 16 x 1 mode	$T_{SHCKO16}$	0.67	1.38	1.5	1.7	ns, max
Clock CLK to X/Y outputs (WE active) 32 x 1 mode	$T_{SHCKO32}$	0.84	1.66	1.9	2.1	ns, max
Shift-Register Mode Clock CLK to X/Y outputs	T_{REG}	1.25	2.39	2.9	3.2	ns, max
Setup and Hold Times before/after Clock CLK						
F/G address inputs	T_{AS}/T_{AH}	0.19 / 0	0.38 / 0	0.42 / 0	0.47 / 0	ns, min
BX/BY data inputs (DIN)	T_{DS}/T_{DH}	0.44 / 0	0.87 / 0	0.97 / 0	1.09 / 0	ns, min
SR input (WE)	T_{WS}/T_{WH}	0.29 / 0	0.57 / 0	0.7 / 0	0.8 / 0	ns, min
Clock CLK						
Minimum Pulse Width, High	T_{WPH}	0.96	1.9	2.1	2.4	ns, min
Minimum Pulse Width, Low	T_{WPL}	0.96	1.9	2.1	2.4	ns, min
Minimum clock period to meet address write cycle time	T_{WC}	1.92	3.8	4.2	4.8	ns, min
Shift-Register Mode						
Minimum Pulse Width, High	T_{SRPH}	1.0	1.9	2.1	2.4	ns, min
Minimum Pulse Width, Low	T_{SRPL}	1.0	1.9	2.1	2.4	ns, min

Notes:
1. A Zero “0” Hold Time listing indicates no hold time or a negative hold time. Negative values can not be guaranteed “best-case”, but if a “0” is listed, there is no positive hold time.

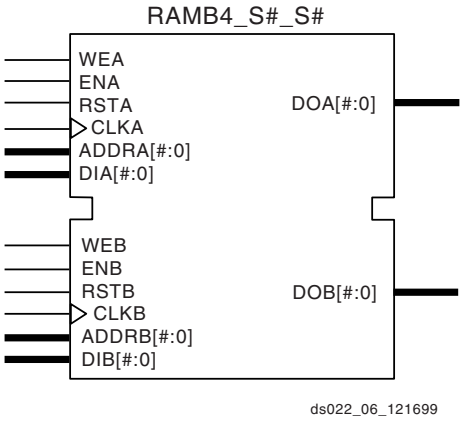


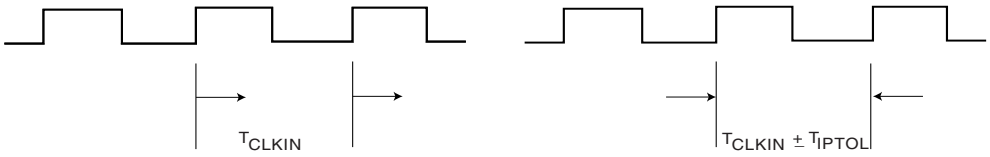
Figure 3: **Dual-Port Block SelectRAM**

DLL Timing Parameters

All devices are 100 percent functionally tested. Because of the difficulty in directly measuring many internal timing parameters, those parameters are derived from benchmark timing patterns. The following guidelines reflect worst-case values across the recommended operating conditions.

Description	Symbol	F_{CLKIN}	Speed Grade						Units
			-8		-7		-6		
			Min	Max	Min	Max	Min	Max	
Input Clock Frequency (CLKDLLHF)	FCLKINHF		60	350	60	320	60	275	MHz
Input Clock Frequency (CLKDLL)	FCLKINLF		25	160	25	160	25	135	MHz
Input Clock Low/High Pulse Width	T_{DLLPW}	≥2□5 MHz	5.0		5.0		5.0		ns
		≥□50 MHz	3.0		3.0		3.0		ns
		≥100 MHz	2.4		2.4		2.4		ns
		≥□150 MHz	2.0		2.0		2.0		ns
		≥□200 MHz	1.8		1.8		1.8		ns
		≥□250 MHz	1.5		1.5		1.5		ns
		≥□300 MHz	1.3		1.3		NA		ns

Period Tolerance: the allowed input clock period change in nanoseconds.



Output Jitter: the difference between an ideal reference clock edge and the actual design.

Phase Offset and Maximum Phase Difference

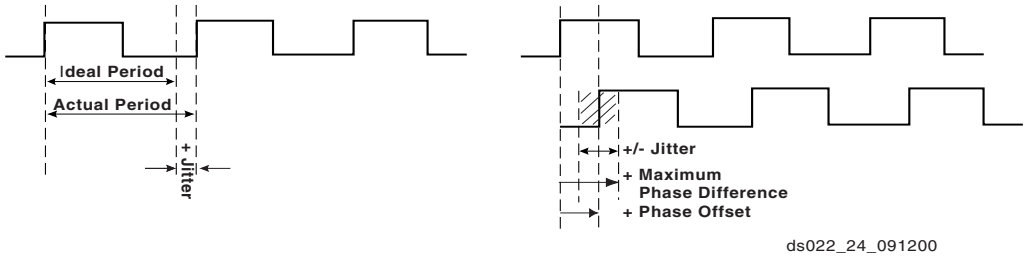


Figure 4: **DLL Timing Waveforms**

Table 8: **HQ240 — XCV600E, XCV1000E**

Pin #	Pin Description	Bank
P66	IO_VREF_L46P	5
P65	IO_L46N	5
P64	IO_L47P_YY	5
P63	IO_L47N_YY	5
P62	M2	NA
P61	VCCO	5
P60	M0	NA
P59	GND	NA
P58	M1	NA
P57	IO_L48N_YY	6
P56	IO_L48P_YY	6
P55	VCCO	6
P54	IO_VREF	6
P53	IO_L49N_Y	6
P52	IO_L49P_Y	6
P51	GND	NA
P50	IO_VREF_L50N_Y	6
P49	IO_L50P_Y	6
P48	IO_VREF	6
P47	IO_VREF_L51N_Y	6
P46	IO_L51P_Y	6
P45	GND	NA
P44	VCCO	6
P43	VCCINT	NA
P42	IO_L52N_YY	6
P41	IO_L52P_YY	6
P40[1]	IO_VREF	6
P39	IO_L53N_Y	6
P38	IO_L53P_Y	6
P37	GND	NA
P36	IO_VREF_L54N_Y	6
P35	IO_L54P_Y	6
P34	IO_L55N_Y	6
P33	IO_VREF_L55P_Y	6
P32	VCCINT	NA
P31	IO	6

Table 8: **HQ240 — XCV600E, XCV1000E**

Pin #	Pin Description	Bank
P30	VCCO	6
P29	GND	NA
P28	IO_L56N_YY	7
P27	IO_L56P_YY	7
P26	IO_VREF	7
P25	VCCO	7
P24	IO_L57N_Y	7
P23	IO_VREF_L57P_Y	7
P22	GND	NA
P21	IO_L58N_Y	7
P20	IO_L58P_Y	7
P19[1]	IO_VREF	7
P18	IO_L59N_YY	7
P17	IO_L59P_YY	7
P16	VCCINT	NA
P15	VCCO	7
P14	GND	NA
P13	IO_L60N_Y	7
P12	IO_VREF_L60P_Y	7
P11	IO_VREF	7
P10	IO_L61N_Y	7
P9	IO_VREF_L61P_Y	7
P8	GND	NA
P7	IO_L62N_Y	7
P6	IO_L62P_Y	7
P5	IO_VREF_L63N_Y	7
P4	IO_L63P_Y	7
P3	IO	7
P2	TMS	NA
P1	GND	NA

Notes:
1. V_{REF} or I/O option only in the XCV1000E; otherwise, I/O option only.

Table 12: **BG432 — XCV300E, XCV400E, XCV600E**

Bank	Pin Description	Pin #
6	IO	AA30
6	IO	AC30
6	IO	AD29
6	IO	U31
6	IO	W28
6	IO_L103N_YY	AJ30
6	IO_L103P_YY	AH30
6	IO_L104N	AG28
6	IO_L104P	AH31
6	IO_L105N_Y	AG29
6	IO_L105P_Y	AG30
6	IO_VREF_L106N_Y	AF28
6	IO_L106P_Y	AG31
6	IO_L107N	AF29
6	IO_L107P	AF30
6	IO_L108N_Y	AE28
6	IO_L108P_Y	AF31
6	IO_VREF_L109N_YY	AE30
6	IO_L109P_YY	AD28
6	IO_L110N_Y	AD30
6	IO_L110P_Y	AD31
6	IO_VREF_L111N_Y	AC28[1]
6	IO_L111P_Y	AC29
6	IO_VREF_L112N_YY	AB28
6	IO_L112P_YY	AB29
6	IO_L113N_YY	AB31
6	IO_L113P_YY	AA29
6	IO_L114N_Y	Y28
6	IO_L114P_Y	Y29
6	IO_L115N_Y	Y30
6	IO_L115P_Y	Y31
6	IO_L116N_Y	W29
6	IO_L116P_Y	W30
6	IO_VREF_L117N_YY	V28
6	IO_L117P_YY	V29
6	IO_L118N_Y	V30

Table 12: **BG432 — XCV300E, XCV400E, XCV600E**

Bank	Pin Description	Pin #
6	IO_L118P_Y	U29
6	IO_VREF_L119N_Y	U28[2]
6	IO_L119P_Y	U30
6	IO	T30
7	IO	C30
7	IO	H29
7	IO	H31
7	IO	L29
7	IO	M31
7	IO	R28
7	IO_L120N_YY	T31
7	IO_L120P_YY	R29
7	IO_L121N_Y	R30
7	IO_VREF_L121P_Y	R31[2]
7	IO_L122N_Y	P29
7	IO_L122P_Y	P28
7	IO_L123N_YY	P30
7	IO_VREF_L123P_YY	N30
7	IO_L124N_Y	N28
7	IO_L124P_Y	N31
7	IO_L125N_Y	M29
7	IO_L125P_Y	M28
7	IO_L126N_Y	M30
7	IO_L126P_Y	L30
7	IO_L127N_YY	K31
7	IO_L127P_YY	K30
7	IO_L128N_YY	K28
7	IO_VREF_L128P_YY	J30
7	IO_L129N_Y	J29
7	IO_VREF_L129P_Y	J28[1]
7	IO_L130N_Y	H30
7	IO_L130P_Y	G30
7	IO_L131N_YY	H28
7	IO_VREF_L131P_YY	F31
7	IO_L132N_Y	G29

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
1	IO_L43N_Y	C5	
1	IO_VREF_L43P_Y	E7	3
1	IO_WRITE_L44N_YY	D6	
1	IO_CS_L44P_YY	A2	
2	IO	D3	
2	IO	F3	
2	IO	G1	
2	IO	J2	
2	IO_DOUT_BUSY_L45P_YY	D4	
2	IO_DIN_D0_L45N_YY	E4	
2	IO_L46P_Y	F5	
2	IO_VREF_L46N_Y	B3	3
2	IO_L47P_Y	F4	
2	IO_L47N_Y	C1	
2	IO_VREF_L48P_Y	G5	
2	IO_L48N_Y	E3	
2	IO_L49P_Y	D2	
2	IO_L49N_Y	G4	
2	IO_L50P_Y	H5	
2	IO_L50N_Y	E2	
2	IO_VREF_L51P_YY	H4	
2	IO_L51N_YY	G3	
2	IO_L52P_Y	J5	
2	IO_VREF_L52N_Y	F1	1
2	IO_L53P_Y	J4	
2	IO_L53N_Y	H3	
2	IO_VREF_L54P_Y	K5	4
2	IO_L54N_Y	H2	
2	IO_L55P_Y	J3	
2	IO_L55N_Y	K4	
2	IO_VREF_L56P_YY	L5	
2	IO_D1_L56N_YY	K3	
2	IO_D2_L57P_YY	L4	
2	IO_L57N_YY	K2	

Table 14: **BG560 — XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin#	See Note
2	IO_L58P_Y	M5	
2	IO_L58N_Y	L3	
2	IO_L59P_Y	L1	
2	IO_L59N_Y	M4	
2	IO_VREF_L60P_Y	N5	3
2	IO_L60N_Y	M2	
2	IO_L61P_Y	N4	
2	IO_L61N_Y	N3	
2	IO_L62P_Y	N2	
2	IO_L62N_Y	P5	
2	IO_VREF_L63P_YY	P4	
2	IO_D3_L63N_YY	P3	
2	IO_L64P_Y	P2	
2	IO_L64N_Y	R5	
2	IO_L65P_Y	R4	
2	IO_L65N_Y	R3	
2	IO_VREF_L66P_Y	R1	
2	IO_L66N_Y	T4	
2	IO_L67P_Y	T5	
2	IO_VREF_L67N_Y	T3	2
2	IO_L68P_YY	T2	
2	IO_L68N_YY	U3	
3	IO	AE3	
3	IO	AF3	
3	IO	AH3	
3	IO	AK3	
3	IO_VREF_L69P_Y	U1	2
3	IO_L69N_Y	U2	
3	IO_L70P_Y	V2	
3	IO_VREF_L70N_Y	V4	
3	IO_L71P_Y	V5	
3	IO_L71N_Y	V3	
3	IO_L72P_Y	W1	
3	IO_L72N_Y	W3	

Table 15: **BG560 Differential Pin Pair Summary**
XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
47	2	F4	C1	14	-
48	2	G5	E3	15	VREF
49	2	D2	G4	16	-
50	2	H5	E2	15	-
51	2	H4	G3	√	VREF
52	2	J5	F1	17	VREF
53	2	J4	H3	14	-
54	2	K5	H2	18	VREF
55	2	J3	K4	19	-
56	2	L5	K3	√	D1
57	2	L4	K2	√	D2
58	2	M5	L3	17	-
59	2	L1	M4	14	-
60	2	N5	M2	15	VREF
61	2	N4	N3	16	-
62	2	N2	P5	15	-
63	2	P4	P3	√	D3
64	2	P2	R5	17	-
65	2	R4	R3	14	-
66	2	R1	T4	18	VREF
67	2	T5	T3	19	VREF
68	2	T2	U3	√	-
69	3	U1	U2	19	VREF
70	3	V2	V4	18	VREF
71	3	V5	V3	14	-
72	3	W1	W3	17	-
73	3	W4	W5	√	VREF
74	3	Y3	Y4	15	-
75	3	AA1	Y5	16	-
76	3	AA3	AA4	15	VREF
77	3	AB3	AA5	14	-

Table 15: **BG560 Differential Pin Pair Summary**
XCV400E, XCV600E, XCV1000E, XCV1600E, XCV2000E

Pair	Bank	P Pin	N Pin	AO	Other Functions
78	3	AC1	AB4	17	-
79	3	AC3	AB5	√	D5
80	3	AC4	AD3	√	VREF
81	3	AE1	AC5	4	-
82	3	AD4	AF1	18	VREF
83	3	AF2	AD5	14	-
84	3	AG2	AE4	20	VREF
85	3	AH1	AE5	√	VREF
86	3	AF4	AJ1	15	-
87	3	AJ2	AF5	14	-
88	3	AG4	AK2	15	VREF
89	3	AJ3	AG5	14	-
90	3	AL1	AH4	14	VREF
91	3	AJ4	AH5	√	INIT
92	4	AL4	AJ6	√	-
93	4	AK5	AN3	8	VREF
94	4	AL5	AJ7	√	-
95	4	AM4	AM5	√	VREF
96	4	AK7	AL6	3	-
97	4	AM6	AN6	√	-
98	4	AL7	AJ9	√	VREF
99	4	AN7	AL8	9	VREF
100	4	AM8	AJ10	7	-
101	4	AL9	AM9	7	VREF
102	4	AK10	AN9	2	-
103	4	AL10	AM10	√	VREF
104	4	AL11	AJ12	√	-
105	4	AN11	AK12	8	-
106	4	AL12	AM12	√	-
107	4	AK13	AL13	√	VREF
108	4	AM13	AN13	3	-

Table 17: **FG256 Differential Pin Pair Summary XCV50E, XCV100E, XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
19	2	C15	D14	√	DIN, D0
20	2	B16	E13	6	VREF
21	2	C16	E14	√	-
22	2	F13	E15	1	VREF
23	2	F12	D16	5	-
24	2	F14	E16	3	D1
25	2	F15	G13	√	D2
26	2	F16	G12	6	-
27	2	G15	G14	√	-
28	2	H13	G16	3	D3
29	2	J13	H15	4	-
30	2	H14	H16	√	-
31	3	K15	J14	4	-
32	3	J16	K16	3	VREF
33	3	K12	L15	√	-
34	3	K13	L16	6	-
35	3	K14	M16	√	D5
36	3	N16	L13	3	VREF
37	3	P16	L12	5	-
38	3	M15	L14	1	VREF
39	3	M14	R16	√	-
40	3	M13	T15	6	VREF
41	3	N14	N15	√	INIT
42	4	T14	P13	√	-
43	4	P12	R13	7	VREF
44	4	N12	T13	√	-
45	4	T12	P11	√	VREF
46	4	R12	N11	2	-
47	4	T11	M11	√	VREF
48	4	R11	T10	√	-
49	4	R10	M10	1	-
50	4	P9	T9	1	VREF
51	4	N10	R9	1	-
52	5	N9	T8	NA	IO_LVDS_DLL
53	5	R7	P8	1	VREF
54	5	P7	T6	1	-

Table 17: **FG256 Differential Pin Pair Summary XCV50E, XCV100E, XCV200E, XCV300E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
55	5	M7	R6	√	-
56	5	P6	R5	√	VREF
57	5	N6	T5	2	-
58	5	M6	T4	√	VREF
59	5	T3	P5	√	-
60	5	T2	N5	7	VREF
61	6	R1	M3	√	-
62	6	N2	M4	6	VREF
63	6	P1	L5	√	-
64	6	L3	N1	1	VREF
65	6	L4	M2	5	-
66	6	K4	M1	3	VREF
67	6	L1	L2	√	-
68	6	K1	K3	6	-
69	6	K5	K2	√	-
70	6	J1	J3	3	VREF
71	6	H1	J4	4	-
72	7	H4	G1	√	-
73	7	H2	G5	4	-
74	7	H3	G4	3	VREF
75	7	F5	G2	√	-
76	7	F1	F4	6	-
77	7	F2	G3	√	-
78	7	D1	E1	3	VREF
79	7	E2	E4	5	-
80	7	C1	F3	1	VREF
81	7	E3	D2	√	-
82	7	A2	B1	6	VREF

Notes:
1. AO in the XCV50E, 200E, 300E.
2. AO in the XCV50E, 200E.
3. AO in the XCV50E, 300E.
4. AO in the XCV100E, 200E.
5. AO in the XCV200E.
6. AO in the XCV100E.
7. AO in the XCV50E.

Table 20: **FG676 — XCV400E, XCV600E**

Bank	Pin Description	Pin #
0	VCCO	H10
1	VCCO	J15
1	VCCO	J14
1	VCCO	H18
1	VCCO	H17
1	VCCO	H16
1	VCCO	H15
2	VCCO	N18
2	VCCO	M19
2	VCCO	M18
2	VCCO	L19
2	VCCO	K19
2	VCCO	J19
3	VCCO	V19
3	VCCO	U19
3	VCCO	T19
3	VCCO	R19
3	VCCO	R18
3	VCCO	P18
4	VCCO	W18
4	VCCO	W17
4	VCCO	W16
4	VCCO	W15
4	VCCO	V15
4	VCCO	V14
5	VCCO	W9
5	VCCO	W12
5	VCCO	W11
5	VCCO	W10
5	VCCO	V13
5	VCCO	V12
6	VCCO	V8
6	VCCO	U8
6	VCCO	T8
6	VCCO	R9
6	VCCO	R8
6	VCCO	P9

Table 20: **FG676 — XCV400E, XCV600E**

Bank	Pin Description	Pin #
7	VCCO	N9
7	VCCO	M9
7	VCCO	M8
7	VCCO	L8
7	VCCO	K8
7	VCCO	J8
NA	GND	V25
NA	GND	V2
NA	GND	U17
NA	GND	U16
NA	GND	U15
NA	GND	U14
NA	GND	U13
NA	GND	U12
NA	GND	U11
NA	GND	U10
NA	GND	T17
NA	GND	T16
NA	GND	T15
NA	GND	T14
NA	GND	T13
NA	GND	T12
NA	GND	T11
NA	GND	T10
NA	GND	R17
NA	GND	R16
NA	GND	R15
NA	GND	R14
NA	GND	R13
NA	GND	R12
NA	GND	R11
NA	GND	R10
NA	GND	P25
NA	GND	P17
NA	GND	P16
NA	GND	P15

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
4	IO_L147N_YY	AW7
4	IO_L148P_Y	AY7
4	IO_L148N_Y	BB8
4	IO_L149P_Y	BA9
4	IO_L149N_Y	AV8
4	IO_L150P_YY	AW8
4	IO_L150N_YY	BA10
4	IO_VREF_L151P_YY	BB10
4	IO_L151N_YY	AY8
4	IO_L152P_Y	AV9
4	IO_L152N_Y	BA11
4	IO_VREF_L153P_Y	BB11[2]
4	IO_L153N_Y	AW9
4	IO_L154P_YY	AY9
4	IO_L154N_YY	BA12
4	IO_VREF_L155P_YY	BB12
4	IO_L155N_YY	AV10
4	IO_L156P_Y	BA13
4	IO_L156N_Y	AW10
4	IO_L157P_Y	BB13
4	IO_L157N_Y	AY10
4	IO_VREF_L158P_YY	AV11
4	IO_L158N_YY	BA14
4	IO_L159P_YY	AW11
4	IO_L159N_YY	BB14
4	IO_L160P_Y	AV12
4	IO_L160N_Y	BA15
4	IO_L161P_Y	AW12
4	IO_L161N_Y	AY15
4	IO_L162P_Y	AW13
4	IO_L162N_Y	BB15
4	IO_L163P_Y	AV14
4	IO_L163N_Y	BA16
4	IO_L164P_YY	AW14
4	IO_L164N_YY	AY16
4	IO_VREF_L165P_YY	BB16
4	IO_L165N_YY	AV15
4	IO_L166P_Y	AY17
4	IO_L166N_Y	AW15
4	IO_L167P_Y	BB17
4	IO_L167N_Y	AU16
4	IO_L168P_YY	AV16
4	IO_L168N_YY	AY18
4	IO_VREF_L169P_YY	AW16
4	IO_L169N_YY	BA18
4	IO_L170P_Y	BB19
4	IO_L170N_Y	AW17
4	IO_L171P_Y	AY19
4	IO_L171N_Y	AV18
4	IO_L172P_YY	AW18
4	IO_L172N_YY	BB20
4	IO_VREF_L173P_YY	AY20
4	IO_L173N_YY	AV19
4	IO_L174P_Y	BB21
4	IO_L174N_Y	AW19
4	IO_VREF_L175P_Y	AY21[1]
4	IO_L175N_Y	AV20
4	IO_LVDS_DLL_L176P	AW20
5	GCK1	AY22
5	IO	AV24
5	IO	AV34
5	IO	AW27
5	IO	AW36
5	IO	AY23
5	IO	AY31
5	IO	AY33
5	IO	BA26
5	IO	BA29
5	IO	BA33
5	IO	BB25
5	IO_LVDS_DLL_L176N	AW21
5	IO_L177P_Y	BB22
5	IO_VREF_L177N_Y	AW22[1]

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
5	IO_L178P_Y	BB23
5	IO_L178N_Y	AW23
5	IO_L179P_YY	AV23
5	IO_VREF_L179N_YY	BA23
5	IO_L180P_YY	AW24
5	IO_L180N_YY	BB24
5	IO_L181P_Y	AY24
5	IO_L181N_Y	AW25
5	IO_L182P_Y	BA24
5	IO_L182N_Y	AV25
5	IO_L183P_YY	AW26
5	IO_VREF_L183N_YY	AY25
5	IO_L184P_YY	AV26
5	IO_L184N_YY	BA25
5	IO_L185P_Y	BB26
5	IO_L185N_Y	AV27
5	IO_L186P_Y	AY26
5	IO_L186N_Y	AU27
5	IO_L187P_YY	AW28
5	IO_VREF_L187N_YY	BB27
5	IO_L188P_YY	AY27
5	IO_L188N_YY	AV28
5	IO_L189P_Y	BA27
5	IO_L189N_Y	AW29
5	IO_L190P_Y	BB28
5	IO_L190N_Y	AV29
5	IO_L191P_Y	AY28
5	IO_L191N_Y	AW30
5	IO_L192P_Y	BA28
5	IO_L192N_Y	AW31
5	IO_L193P_YY	BB29
5	IO_L193N_YY	AV31
5	IO_L194P_YY	AY29
5	IO_VREF_L194N_YY	AY32
5	IO_L195P_Y	AW32
5	IO_L195N_Y	BB30
5	IO_L196P_Y	AV32

Table 24: **FG860 — XCV1000E, XCV1600E, XCV2000E**

Bank	Pin Description	Pin #
5	IO_L196N_Y	AY30
5	IO_L197P_YY	BA30
5	IO_VREF_L197N_YY	AW33
5	IO_L198P_YY	BB31
5	IO_L198N_YY	AV33
5	IO_L199P_Y	AY34
5	IO_VREF_L199N_Y	BA31[2]
5	IO_L200P_Y	AW34
5	IO_L200N_Y	BB32
5	IO_L201P_YY	BA32
5	IO_VREF_L201N_YY	AY35
5	IO_L202P_YY	BB33
5	IO_L202N_YY	AW35
5	IO_L203P_Y	AV35
5	IO_L203N_Y	BB34
5	IO_L204P_Y	AY36
5	IO_L204N_Y	BA34
5	IO_L205P_YY	BB35
5	IO_VREF_L205N_YY	AV36
5	IO_L206P_YY	BA35
5	IO_L206N_YY	AY37
5	IO_L207P_Y	BB36
5	IO_L207N_Y	BA36
5	IO_L208P_Y	AW37
5	IO_VREF_L208N_Y	BB37
5	IO_L209P_Y	BA37
5	IO_L209N_Y	AY38
5	IO_L210P_Y	BB38
5	IO_L210N_Y	AY39
6	IO	AA40
6	IO	AB41
6	IO	AC42
6	IO	AD39
6	IO	AE40
6	IO	AF38
6	IO	AF40

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
5	IO_L182N	AF13
5	IO_L183P	AH14
5	IO_L183N	AJ14
5	IO_L184P_YY	AE14
5	IO_VREF_L184N_YY	AG13
5	IO_L185P_YY	AK13
5	IO_L185N_YY	AD13
5	IO_L186P	AE13
5	IO_L186N	AF12
5	IO_L187P	AC13
5	IO_L187N	AA13
5	IO_L188P_YY	AA12
5	IO_VREF_L188N_YY	AJ12[1]
5	IO_L189P_YY	AB12
5	IO_L189N_YY	AE11
5	IO_L190P	AK12[4]
5	IO_L190N	Y13[4]
5	IO_L191P	AG11
5	IO_L191N	AF11
5	IO_L192P	AH11
5	IO_L192N	AJ11
5	IO_L193P_YY	AE12[4]
5	IO_L193N_YY	AG10[4]
5	IO_L194P_YY	AD12
5	IO_L194N_YY	AK11
5	IO_L195P_YY	AJ10
5	IO_VREF_L195N_YY	AC12
5	IO_L196P_YY	AK10
5	IO_L196N_YY	AD11
5	IO_L197P_YY	AJ9
5	IO_L197N_YY	AE9
5	IO_L198P_YY	AH10
5	IO_VREF_L198N_YY	AF9
5	IO_L199P_YY	AH9
5	IO_L199N_YY	AK9
5	IO_L200P	AF8
5	IO_L200N	AB11

Table 26: **FG900 — XCV600E, XCV1000E, XCV1600E**

Bank	Pin Description	Pin #
5	IO_L201P	AC11
5	IO_L201N	AG8
5	IO_L202P_YY	AK8
5	IO_VREF_L202N_YY	AF7
5	IO_L203P_YY	AG7
5	IO_L203N_YY	AK7
5	IO_L204P	AJ7
5	IO_L204N	AD10
5	IO_L205P	AH6
5	IO_L205N	AC10
5	IO_L206P_YY	AD9
5	IO_VREF_L206N_YY	AG6
5	IO_L207P_YY	AB10
5	IO_L207N_YY	AJ5
5	IO_L208P	AD8[4]
5	IO_L208N	AK5[4]
5	IO_L209P	AC9
5	IO_VREF_L209N	AJ4[1]
5	IO_L210P	AG5
5	IO_L210N	AK4
5	IO_L211P_YY	AH5[3]
5	IO_L211N_YY	AG3[4]
6	IO	T2[4]
6	IO	T10[4]
6	IO	U1
6	IO	U4[5]
6	IO	U6[4]
6	IO	U7[4]
6	IO	V1[4]
6	IO	V5[5]
6	IO	V8
6	IO	Y10[4]
6	IO	AA4[4]
6	IO	AB5[5]
6	IO	AB7[4]
6	IO	AC3[5]

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
NA	VCCO_7	K5
NA	VCCO_7	F1
NA	VCCO_7	T11
NA	VCCO_7	T12
NA	VCCO_7	R11
NA	VCCO_7	R12
NA	VCCO_7	P3
NA	VCCO_7	P11
NA	VCCO_7	P12
NA	VCCO_7	N11
NA	GND	K32
NA	GND	R4
NA	GND	AN1
NA	GND	AM11
NA	GND	AK5
NA	GND	AH28
NA	GND	AD32
NA	GND	AA20
NA	GND	Y20
NA	GND	W19
NA	GND	V19
NA	GND	U20
NA	GND	T20
NA	GND	R19
NA	GND	P19
NA	GND	H8
NA	GND	F12
NA	GND	C2
NA	GND	B1
NA	GND	A7
NA	GND	AP1
NA	GND	AN2
NA	GND	AM15

Table 28: **FG1156 — XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Bank	Pin Description	Pin #
NA	GND	AK17
NA	GND	AH34
NA	GND	AC6
NA	GND	AA21
NA	GND	Y21
NA	GND	W20
NA	GND	V20
NA	GND	U21
NA	GND	T21
NA	GND	R20
NA	GND	P20
NA	GND	H16
NA	GND	F23
NA	GND	C3
NA	GND	B2
NA	GND	A28
NA	GND	AP34
NA	GND	AM3
NA	GND	AL31
NA	GND	AH7
NA	GND	AD3
NA	GND	AA19
NA	GND	Y19
NA	GND	W18
NA	GND	V18
NA	GND	U19
NA	GND	T19
NA	GND	R18
NA	GND	P18
NA	GND	J26
NA	GND	F6
NA	GND	C1
NA	GND	C34
NA	GND	A3

Table 29: **FG1156 Differential Pin Pair Summary: XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
153	3	AD31	AF33	3200 2600 2000 1600 1000	VREF
154	3	AC28	AF31	3200 2600 1600 1000	-
155	3	AC27	AF32	3200 2600 1600	-
156	3	AE29	AD28	2600 1000	VREF
157	3	AD30	AG32	3200 2600 2000 1600 1000	-
158	3	AC26	AH33	2000 1600	-
159	3	AD26	AF30	3200 2600 2000 1600 1000	VREF
160	3	AC25	AH32	2600 2000 1000	-
161	3	AE28	AL34	3200 2600 2000	-
162	3	AG30	AD27	3200 2600 1600 1000	-
163	3	AF29	AK34	3200 2600 2000 1600 1000	-
164	3	AD25	AE27	3200 2600 2000 1600	-
165	3	AJ33	AH31	2600 2000 1000	VREF
166	3	AE26	AL33	3200 2600 1600 1000	-
167	3	AF28	AL32	2600 1600	-
168	3	AJ31	AF27	3200 2600 1600 1000	VREF
169	3	AG29	AJ32	2600 2000 1000	-
170	3	AK33	AH30	3200 2600 2000	-
171	3	AK32	AK31	3200 2600 2000 1600 1000	INIT

Table 29: **FG1156 Differential Pin Pair Summary: XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
172	4	AP31	AK29	3200 2600 2000 1600 1000	-
173	4	AP30	AN31	3200 1600 1000	-
174	4	AH27	AN30	3200 2000 1000	-
175	4	AM30	AK28	3200 2000 1000	VREF
176	4	AG26	AN29	3200 2600 1000	-
177	4	AF25	AM29	3200 2600 2000 1600 1000	-
178	4	AL29	AL28	3200 2600 2000 1600 1000	VREF
179	4	AE24	AN28	2000 1600	-
180	4	AJ27	AH26	3200 1000	-
181	4	AG25	AK27	3200 1000	-
182	4	AM28	AF24	3200 2600	-
183	4	AJ26	AP27	3200 2600 2000 1600 1000	-
184	4	AK26	AN27	3200 2600 2000 1600 1000	VREF
185	4	AE23	AM27	3200 1600	-
186	4	AL26	AP26	3200 2000 1000	-
187	4	AN26	AJ25	3200 2000 1000	VREF
188	4	AG24	AP25	3200 2600	-
189	4	AF23	AM26	3200 2600 2000 1600 1000	-
190	4	AJ24	AN25	3200 2600 2000 1600 1000	VREF
191	4	AE22	AM25	2600 1600 1000	-

Table 29: **FG1156 Differential Pin Pair Summary: XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
311	7	P2	R8	2600 2000 1000	-
312	7	N1	R9	3200 2600 2000	-
313	7	R10	P4	3200 2600 1600 1000	-
314	7	N2	P8	3200 2600 2000 1600 1000	-
315	7	P7	P6	3200 2600 2000 1600	-
316	7	N4	M1	2600 2000 1000	VREF
317	7	N3	N6	3200 1600 1000	-
318	7	M2	P9	2600 1600	-
319	7	M3	N7	3200 2600 1600 1000	-
320	7	M4	P10	2000 1000	-
321	7	N8	L1	3200 2600 2000	-
322	7	N9	L2	3200 2600 2000 1600 1000	-
323	7	K1	M7	2000 1600 1000	VREF
324	7	L4	M8	3200 1600 1000	-
325	7	L5	J1	3200 2600 2000 1600 1000	-
326	7	K3	J2	3200 2600 2000 1600 1000	VREF
327	7	J3	L7	3200 2600 1600 1000	-
328	7	H2	M9	3200 2600 1600	-
329	7	K6	J4	2600 1000	VREF
330	7	G2	L8	3200 2600 2000 1600 1000	-

Table 29: **FG1156 Differential Pin Pair Summary: XCV1000E, XCV1600E, XCV2000E, XCV2600E, XCV3200E**

Pair	Bank	P Pin	N Pin	AO	Other Functions
331	7	K7	H3	2000 1600	-
332	7	J5	G3	3200 2600 2000 1600 1000	VREF
333	7	H5	L9	2600 2000 1000	-
334	7	H4	J6	3200 2600 2000	-
335	7	K8	G4	3200 2600 1600 1000	-
336	7	F2	J7	3200 2600 2000 1600 1000	-
337	7	L10	F3	3200 2600 2000 1600	-
338	7	H6	E1	2600 2000 1000	VREF
339	7	E2	G5	3200 2600 1600 1000	-
340	7	D1	K9	2600 1600	-
341	7	J8	E3	3200 2600 1600 1000	VREF
342	7	D2	E4	2600 2000 1000	-
343	7	D3	F4	3200 2600 2000	-